



PJMBZ5V6 / PJMBZ6V2 / PJMBZ6V8

DUAL TVS ZENER FOR ESD / TRANSIENT PROTECTION

VOLTAGE 5.6 to 6.8 Volts **POWER** 150 Watts

SOT-23 Unit: inch (mm)

FEATURES

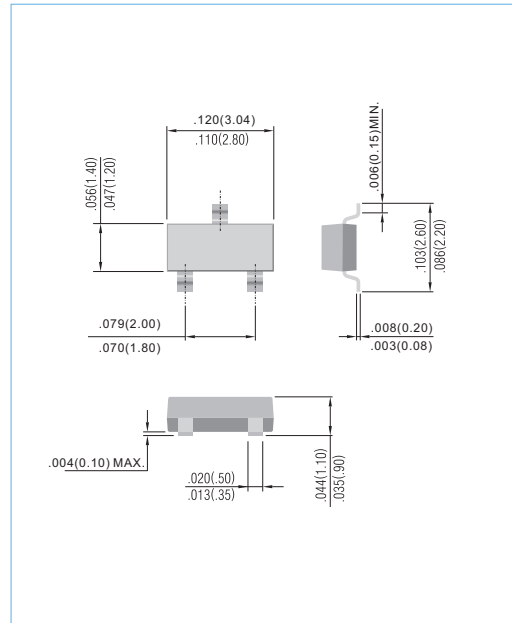
- Working Peak Reverse Voltage Range - 5.6 to 6.8V
- Maximum Leakage Current of 5uA
- IEC61000-4-2 Compliance 15kV Air, 8kV Contact Discharge
- In compliance with EU RoHS 2002/95/EC directives

APPLICATIONS

- Data Transmission Line Ports
- Computer Monitor Interface Port Protection
- Portable Consumer Electronics
- Instrumentation Equipment

MECHANICAL DATA

- Case: SOT-23, Plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Apporx. Weight: 0.0003 ounce, 0.0084 gram



MAXIMUM RATINGS

PARAMETER	Symbol	Value	Units
Peak Pulse Power 8x20 usec Waveform	P _{PP}	150	W
Peak Pulse Power 10x1000 usec Waveform		25	
ESD Voltage (HBM)	V _{ESD}	>25	kV
Lead Soldering Temperature (max 10 secs)	T _L	260	°C
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

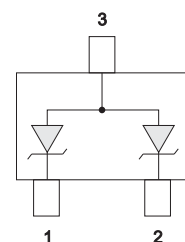


Fig.25



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ELECTRICAL CHARACTERISTICS T_j = 25°C

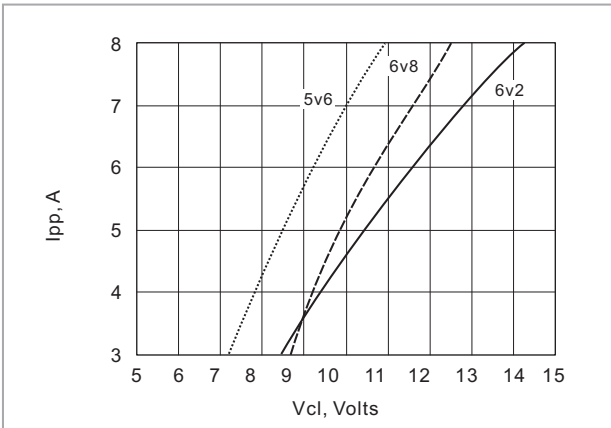
PJMBZ5V6 Marking UA						
PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Reverse Stand-Off Voltage	V _{RWM}		-	-	3.3	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} =1.0 mA I _{BR} =20 mA	5.32	5.4 5.6	5.88	V
Reverse Leakage Current	I _R	V _R =3.3V	-	-	5.0	μA
Clamping Voltage (8x20 usec)	V _{CL}	I _{PP} =5.0 Amps	-	-	9.0	V
Clamping Voltage (10x1000 usec)	V _{CL}	I _{PP} =2.0 Amps	-	-	7.0	V
Off State Junction Capacitance	C _J	0 Vdc Bias f=1MHz Between I/O pins and pin 3	-	-	90	pF

PJMBZ6V2 Marking UB						
PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Reverse Stand-Off Voltage	V _{RWM}		-	-	4.3	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} =1.0 mA I _{BR} =20 mA	5.89	6.2	6.51 6.60	V
Reverse Leakage Current	I _R	V _R =4.3V	-	-	0.5	μA
Clamping Voltage (8x20 usec)	V _{CL}	I _{PP} =5.0 Amps	-	-	11	V
Clamping Voltage (10x1000 usec)	V _{CL}	I _{PP} =2.0 Amps	-	-	8.5	V
Off State Junction Capacitance	C _J	0 Vdc Bias f=1MHz Between I/O pins and pin 3	-	-	70	pF

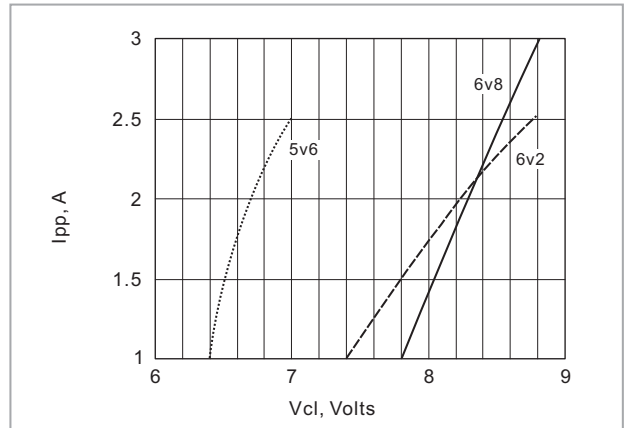
PJMBZ6V8 Marking UC						
PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Reverse Stand-Off Voltage	V _{RWM}		-	-	5.0	V
Reverse Breakdown Voltage	V _{BR}	I _{BR} =1.0 mA I _{BR} =20 mA	6.46	6.8	7.14 7.30	V
Reverse Leakage Current	I _R	V _R =5.0V	-	-	0.5	μA
Clamping Voltage (8x20 usec)	V _{CL}	I _{PP} =5.0 Amps	-	-	10	V
Clamping Voltage (10x1000 usec)	V _{CL}	I _{PP} =2.0 Amps	-	-	9.0	V
Off State Junction Capacitance	C _J	0 Vdc Bias f=1MHz Between I/O pins and pin 3	-	-	100	pF



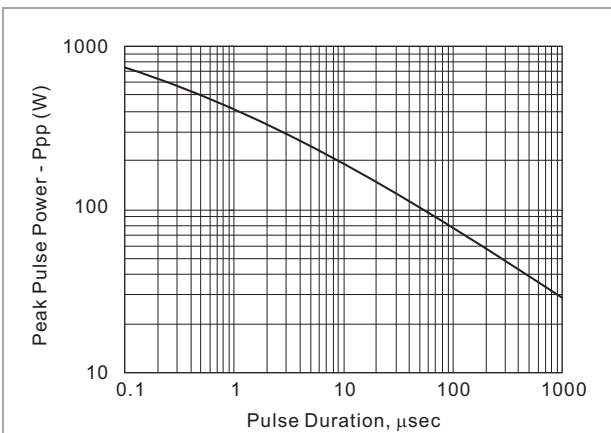
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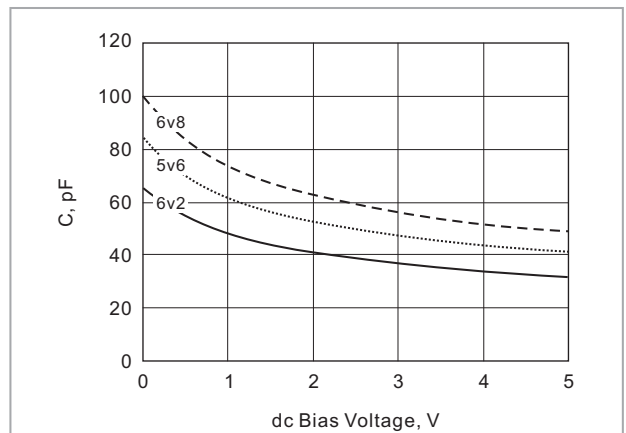
Clamping Voltage vs Ipp 8x20µsec Surge



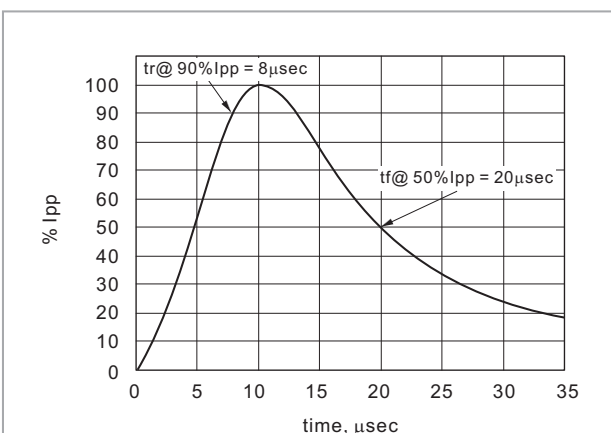
Clamping Voltage vs 10x1000µsec



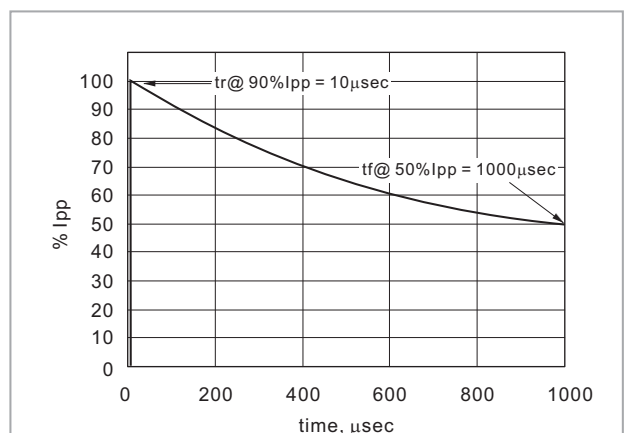
Non-Repetitive Peak Pulse Power vs Pulse Time



Capacitance vs. Biasing Voltage @1MHz



8x20µsec Surge Waveform

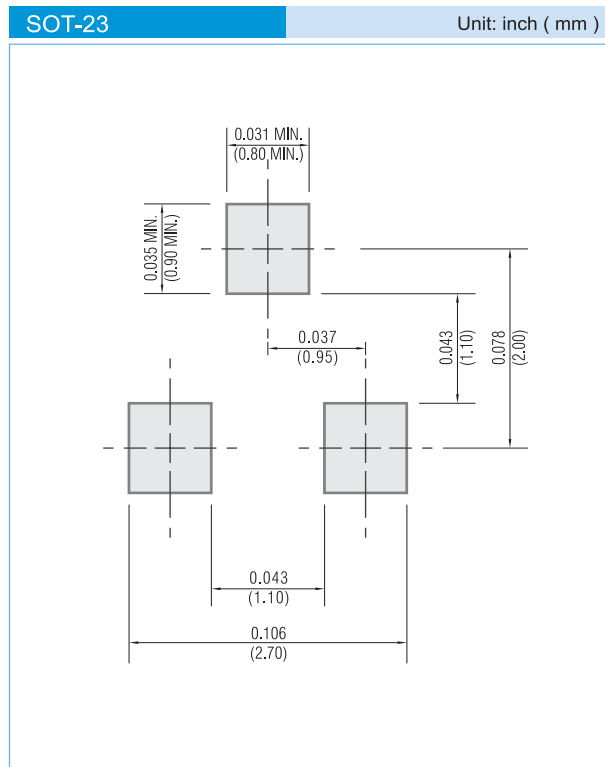


10x1000µsec Waveform



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MOUNTING PAD LAYOUT



ORDER INFORMATION

- Packing information
 - T/R - 12K per 13" plastic Reel
 - T/R - 3K per 7" plastic Reel

LEGAL STATEMENT

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